

# **ULTRAFAST SOFT RECOVERY RECTIFIER DIODE**

# **PRODUCT APPLICATIONS**

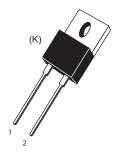
- Anti-Parallel Diode
  - -Switchmode Power Supply
  - -Inverters
- Free Wheeling Diode
  - -Motor Controllers
  - -Converters
  - -Inverters
- · Snubber Diode
- PFC

## **PRODUCT FEATURES**

- Ultrafast Recovery Times
- Soft Recovery Characteristics
  Low Noise Switching
- Popular TO-220 Package or Surface Mount D<sup>2</sup> PAK Pack-
- · Low Forward Voltage
- Low Leakage Current

## **PRODUCT BENEFITS**

- Low Losses
- Cooler Operation
- · Higher Reliability Systems
- · Increased System Power Density





- 1 Cathode
- 2 Anode Back of Case - Cathode

## **MAXIMUM RATINGS**

# All Ratings: $T_C = 25$ °C unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT15D60K(G)	UNIT
V <sub>R</sub>	Maximum D.C. Reverse Voltage		
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	600	Volts
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage		
I <sub>F(AV)</sub>	Maximum Average Forward Current (T <sub>C</sub> = 133°C, Duty Cycle = 0.5)	15	
I <sub>F(RMS)</sub>	RMS Forward Current (Square wave, 50% duty)	32	Amps
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current (T <sub>J</sub> = 45°C, 8.3ms)	110	
$T_J$ , $T_{STG}$	Operating and StorageTemperature Range	-55 to 175	°C
T <sub>L</sub>	Lead Temperature for 10 Sec.	300	

# STATIC ELECTRICAL CHARACTERISTICS

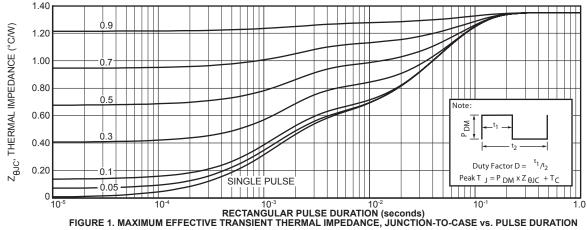
Symbol	Characteristic / Test Conditions		MIN	TYP	MAX	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 15A		1.6	1.8	Volts
		I <sub>F</sub> = 30A		1.9		
		I <sub>F</sub> = 15A, T <sub>J</sub> = 125°C		1.4		
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> = V <sub>R</sub> Rated			250	μA
		$V_R = V_R$ Rated, $T_J = 125$ °C			500	
C <sub>T</sub>	Junction Capacitance, V <sub>R</sub> = 200V			23		pF

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t <sub>rr</sub>	Reverse Recovery Time $I_F = 1A$ , $di_F/dt = -100A/\mu s$ , $V_R = 30V$ , $T_J = 25^{\circ}C$		-	21		ns
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 15A$ , $di_F/dt = -200A/\mu s$ $V_R = 400V$ , $T_C = 25^{\circ}C$	-	80		115
Q <sub>rr</sub>	Reverse Recovery Charge		-	95		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	3	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 15A$ , $di_F/dt = -200A/\mu s$ $V_R = 400V$ , $T_C = 125°C$	-	150		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	520		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	7	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 15A$ , $di_F/dt = -1000A/\mu s$ $V_R = 400V$ , $T_C = 125°C$	-	60		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	810		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	22		Amps

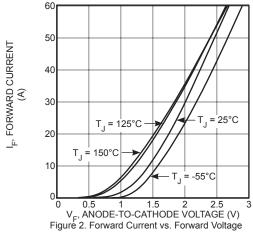
# THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			1.35	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			80	
W <sub>T</sub>	Package Weight		0.07		OZ
			1.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

Microsemi Reserves the right to change, without notice, the specifications and information contained herein.



## **TYPICAL PERFORMANCE CURVES**



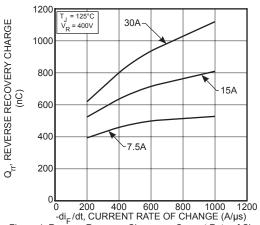
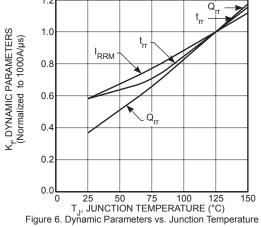
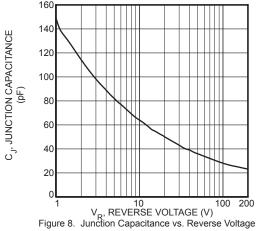
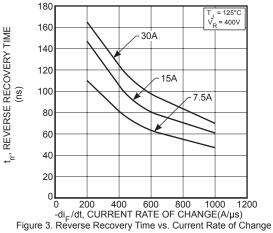


Figure 4. Reverse Recovery Charge vs. Current Rate of Change





# APT15D60K(G)



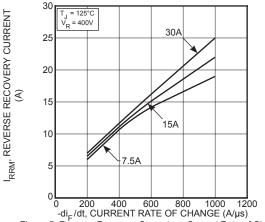


Figure 5. Reverse Recovery Current vs. Current Rate of Change

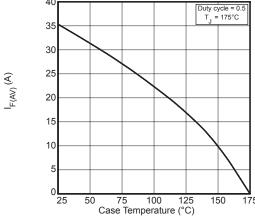


Figure 7. Maximum Average Forward Current vs. CaseTemperature

Figure 9. Diode Test Circuit

- 1 I<sub>F</sub> Forward Conduction Current
- 2 di<sub>-</sub>/dt Rate of Diode Current Change Through Zero Crossing.
- 3 I<sub>RRM</sub> Maximum Reverse Recovery Current
- $\mathbf{5}$   $\mathbf{Q}_{rr}$  Area Under the Curve Defined by  $\mathbf{I}_{RRM}$  and  $\mathbf{t}_{RR}$

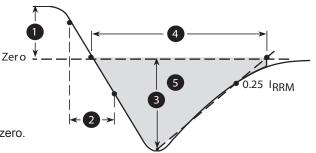
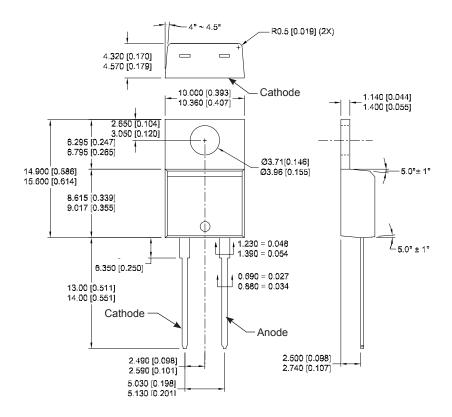


Figure 10. Diode Reverse Recovery Waveform Definition

## TO-220 (K) Package Outline e3 100% Sn



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